

BB207

FM variable capacitance double diode

Rev. 3 — 7 September 2011

Product data sheet

1. Product profile

1.1 General description

The BB207 is a variable capacitance double diode with a common cathode, fabricated in silicon planar technology, and encapsulated in the SOT23 small plastic SMD package.

1.2 Features and benefits

- Excellent linearity
- C_{d(1V)}: 81 pF; C_{d(7.5V)}: 27.6 pF
- lacksquare $C_{d(1V)}$ to $C_{d(7.5V)}$ ratio: min. 2.6
- Very low series resistance
- Small plastic SMD package.

1.3 Applications

■ Electronic tuning in FM-radio.

2. Pinning information

Table 1. Discrete pinning

| Pin | Description | Simplified outline | Symbol | |
|-----|----------------|--------------------|--------|--|
| 1 | anode 1 | - | _ | |
| 2 | anode 2 | 3 | 1 - 2 | |
| 3 | common cathode | 1 2 | | |
| | | | sym032 | |

3. Ordering information

Table 2. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| BB207 | - | plastic surface mounted package; 3 leads | SOT23 |



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4. Marking

Table 3. Marking

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| BB207 | *13 |

^{[1] * =} p: made in Hong Kong.

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------------|------------|------------|------|------|
| Per diode | | | | | |
| V_R | continuous reverse voltage | | - | 15 | V |
| l _F | continuous forward current | | - | 20 | mA |
| T _{stg} | storage temperature | | -55 | +150 | °C |
| Tj | junction temperature | | -55 | +125 | °C |

6. Characteristics

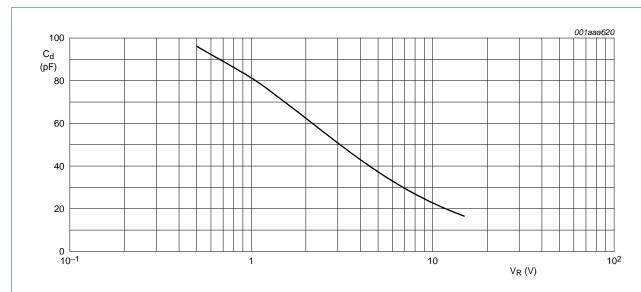
Table 5. Electrical Characteristics

 $T_i = 25$ °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------------------|-------------------------|--|------|------|------|------|
| Per diode | | | | | | |
| I _R | reverse current | V _R = 15 V; see <u>Figure 2</u> | - | _ | 10 | nA |
| | | $V_R = 15 \text{ V}; T_j = 85 ^{\circ}\text{C}; \text{see } \underline{\text{Figure 2}}$ | - | _ | 200 | nA |
| r _s | diode series resistance | $f = 100 \text{ MHz}; V_R = 3 \text{ V}$ | - | 0.2 | 0.4 | Ω |
| C _d | diode capacitance | V _R = 1 V; f = 1 MHz; see Figure 1 | 76 | 81 | 86 | pF |
| | | V _R = 3 V; f = 1 MHz; see Figure 1 | - | 50.5 | _ | pF |
| | | V _R = 7.5 V; f = 1 MHz; see <u>Figure 1</u> | 25.5 | 27.6 | 29.7 | pF |
| | | V _R = 8 V; f = 1 MHz; see <u>Figure 1</u> | - | 26.3 | _ | pF |
| $\frac{C_{d(1V)}}{C_{d(7.5V)}}$ | capacitance ratio | f = 1 MHz | 2.6 | _ | 3.3 | |

^{* =} w: made in China.

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f = 1 MHz; $T_j = 25 \, ^{\circ}\text{C}$.

Fig 1. Diode capacitance as a function of reverse voltage; typical values.

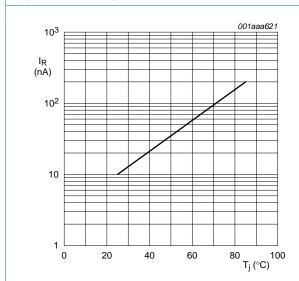


Fig 2. Reverse current as a function of junction temperature; maximum values.

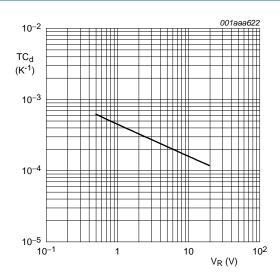


Fig 3. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.

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7. Package outline

Plastic surface-mounted package; 3 leads SOT23 В Α Χ = v M A 3 **→** | w (M) B е detail X 0 1 2 **DIMENSIONS (mm are the original dimensions)** UNIT D Ε Q e₁ H_{E} L_p w max. 0.48 1.1 1.4 1.2 0.45 0.15 3.0 0.55 0.1 0.9 0.38 0.09 2.8 0.15 REFERENCES **EUROPEAN** OUTLINE ISSUE DATE VERSION **PROJECTION** IEC **JEDEC** JEITA -04-11-04 SOT23 TO-236AB 06-03-16

Fig 4. Package outline.

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8. Revision history

Table 6. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------------------------|---------------------------------|--|---|-----------------------|
| BB207 v.3 | 20110907 | Product data sheet | - | BB207 v.2 |
| Modifications: | | of this data sheet has been of NXP Semiconductors. | redesigned to comply v | vith the new identity |
| | Legal texts | have been adapted to the n | ew company name whe | ere appropriate. |
| | - 3 | The state of the s | - · · · · · · · · · · · · · · · · · · · | appropriate. |
| | · · | utline drawings have been u | • • | • • • |
| BB207 v.2 (9397 750 13003) | · · | • | • • | • • • |

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9. Legal information

9.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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